Rectifier Diode
Avalanche Diode

V_{RRM} = 1200-1800 V
$I_{F(RMS)}$ = 160 A
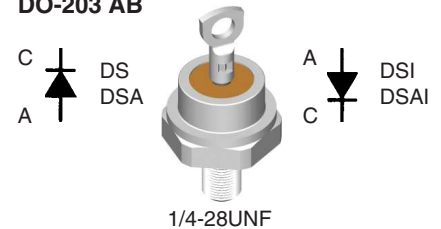$I_{F(AV)M}$ = 110 A

Replacements see page 3

V_{RSM} V	$V_{(BR)min}$ ① V	V_{RRM} V	Anode on stud	Cathode on stud
1300	-	1200	DS 75-12B	DSI 75-12B
1300	1300	1200	DSA 75-12B	DSAI 75-12B
1700	1760	1600	DSA 75-16B	DSAI 75-16B
1900	1950	1800	DSA 75-18B	DSAI 75-18B

① Only for Avalanche Diodes

DO-203 AB

C — DS DSA — A   A — DSI DSAI — C

1/4-28UNF

A = Anode   C = Cathode

Symbol	Test Conditions		Maximum Ratings	
$I_{F(RMS)}$	$T_{VJ} = T_{VJM}$		160	A
$I_{F(AV)M}$	T_{case} = 100°C; 180° sine		110	A
P_{RSM}	DSA(I) types, $T_{VJ} = T_{VJM}$, t_p = 10 µs		20	kW
I_{FSM}	T_{VJ} = 45°C;	t = 10 ms (50 Hz), sine	1400	A
	V_R = 0	t = 8.3 ms (60 Hz), sine	1500	A
	$T_{VJ} = T_{VJM}$	t = 10 ms (50 Hz), sine	1250	A
	V_R = 0	t = 8.3 ms (60 Hz), sine	1310	A
I^2t	T_{VJ} = 45°C	t = 10 ms (50 Hz), sine	9800	A²s
	V_R = 0	t = 8.3 ms (60 Hz), sine	9450	A²s
	$T_{VJ} = T_{VJM}$	t = 10 ms (50 Hz), sine	7820	A²s
	V_R = 0	t = 8.3 ms (60 Hz), sine	7210	A²s
T_{VJ}			-40...+180	°C
T_{VJM}			180	°C
T_{stg}			-40...+180	°C
M_d	Mounting torque		2.4-4.5	Nm
			21-40	lb.in.
Weight			21	g

Symbol	Test Conditions	Characteristic Values	
I_R	$T_{VJ} = T_{VJM}$; $V_R = V_{RRM}$	≤ 6	mA
V_F	I_F = 150 A; T_{VJ} = 25°C	≤ 1.17	V
V_{T0}	For power-loss calculations only	0.75	V
r_T	$T_{VJ} = T_{VJM}$	2	mΩ
R_{thJC}	DC current	0.5	K/W
R_{thJH}	DC current	0.9	K/W
d_S	Creepage distance on surface	4.05	mm
d_A	Strike distance through air	3.9	mm
a	Max. allowable acceleration	100	m/s²

Data according to IEC 60747
IXYS reserves the right to change limits, test conditions and dimensions

Features
- International standard package, JEDEC DO-203 AB (DO-5)
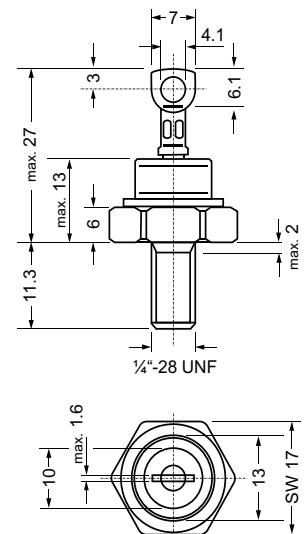- Planar glassivated chips

Applications
- High power rectifiers
- Field supply for DC motors
- Power supplies

Advantages
- Space and weight savings
- Simple mounting
- Improved temperature and power cycling
- Reduced protection circuits

Dimensions in mm (1 mm = 0.0394")

7
4.1
3
6.1
max. 27
max. 13
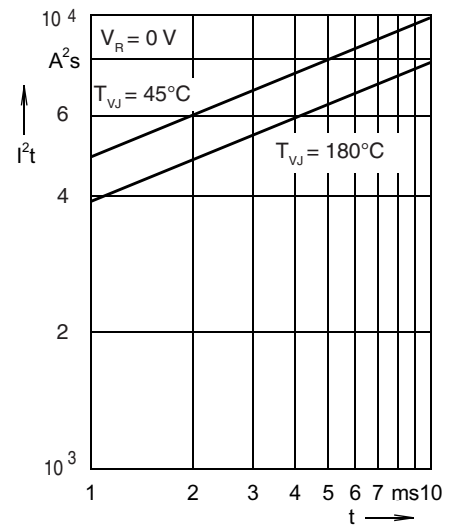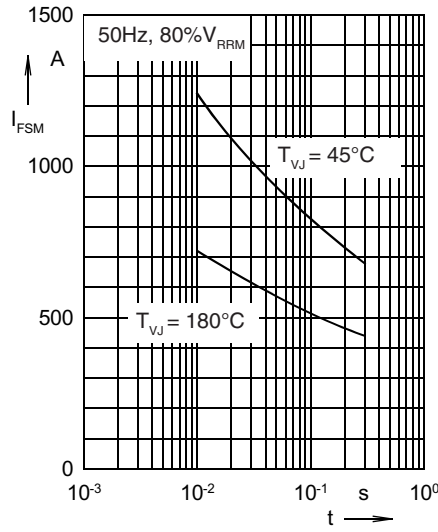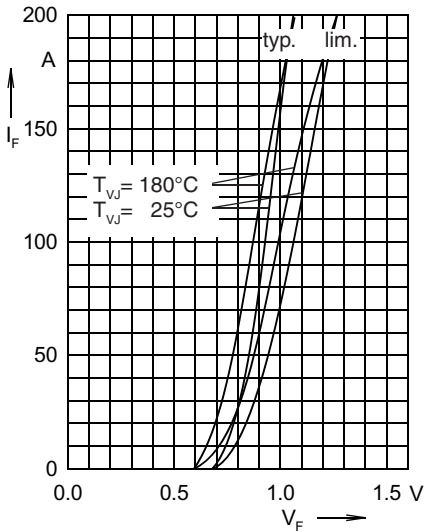6
11.3
max. 2
¼"-28 UNF
max. 1.6
10
13
SW 17

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Fig. 1 Forward characteristics

Fig. 2 Surge overload current
I_{FSM}: crest value, t: duration

Fig. 3 I^2t versus time (1-10 ms)

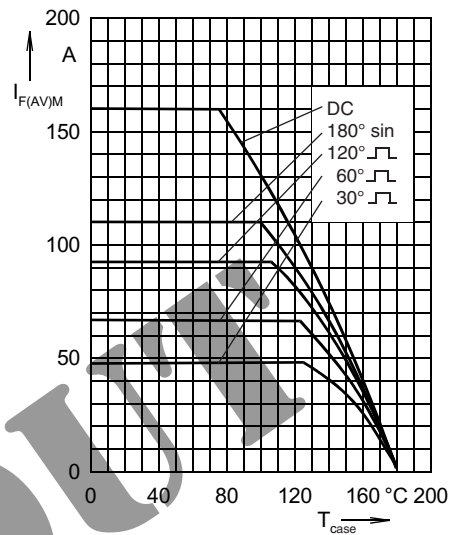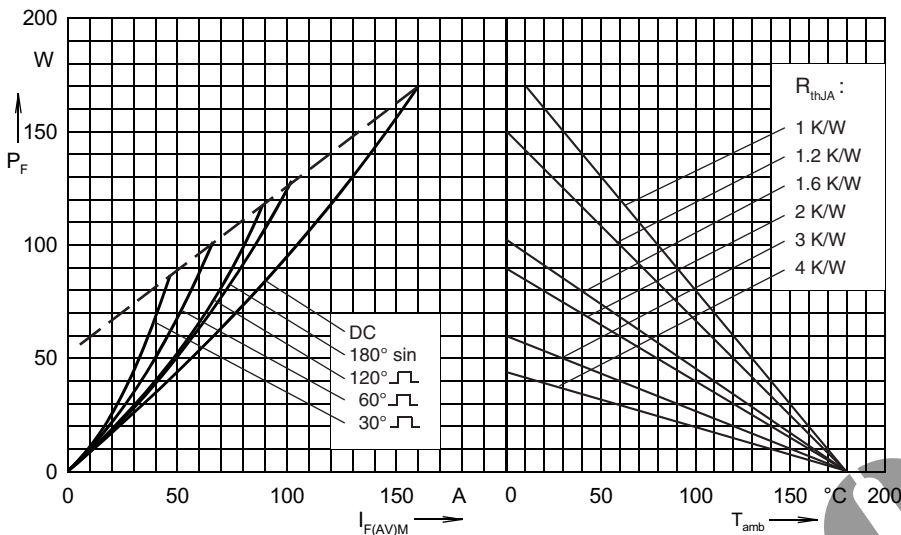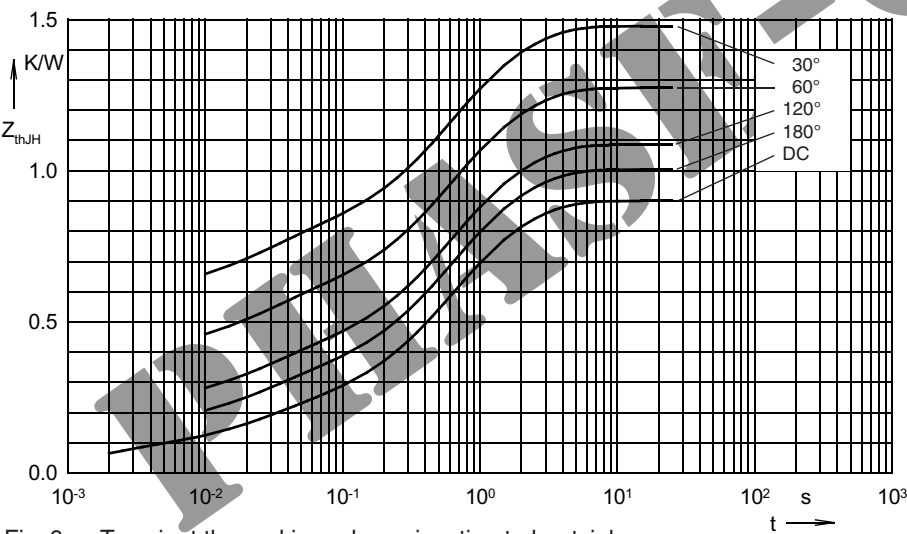Fig. 4 Power dissipation versus forward current and ambient temperature

Fig. 5 Max. forward current at case temperature

Fig. 6 Transient thermal impedance junction to heatsink

R_{thJH} for various conduction angles d:

d	R_{thJH} (K/W)
DC	0.900
180°	1.028
120°	1.085
60°	1.272
30°	1.476

Constants for Z_{thJH} calculation:

i	R_{thi} (K/W)	t_i (s)
1	0.0731	0.0015
2	0.1234	0.0237
3	0.4035	0.4838
4	0.3000	1.5

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Type	Replacements
DSI75-12B	DMA200X1600NA; DMA200XA1600NA
DSAI75-12B	DMA200X1600NA; DMA200XA1600NA; DAA200X1800NA; DAA200XA1800NA
DSAI75-16B	DMA200X1600NA; DMA200XA1600NA; DAA200X1800NA; DAA200XA1800NA
DSAI75-18B	DAA200X1800NA; DAA200XA1800NA
DS75-12B	DMA200X1600NA; DMA200XA1600NA
DSA75-12B	DMA200X1600NA; DMA200XA1600NA; DAA200X1800NA; DAA200XA1800NA
DSA75-16B	DMA200X1600NA; DMA200XA1600NA; DAA200X1800NA; DAA200XA1800NA
DSA75-18B	DAA200X1800NA; DAA200XA1800NA

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